

30V N-Channel Enhancement Mode MOSFET

Voltage

30 V

Current

15 A

Features

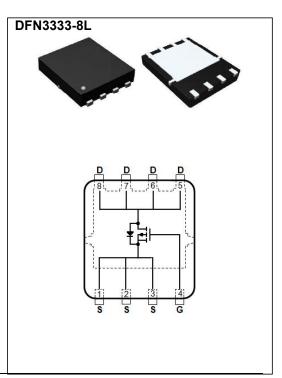
- $R_{DS(ON)}$, $V_{GS}@10V$, $I_{D}@10A<6m\Omega$
- $R_{DS(ON)}$, $V_{GS}@4.5V$, $I_D@8A<9m\Omega$
- High switching speed
- Improved dv/dt capability
- Low Gate Charge
- Low reverse transfer capacitance

Mechanical Data

• Case: DFN3333-8L Package

• Terminals : Solderable per MIL-STD-750, Method 2026

• Approx. Weight: 0.001 ounces, 0.03 grams



Maximum Ratings and Thermal Characteristics (T_A=25°C unless otherwise noted)

PARAMETER		SYMBOL	LIMIT	UNITS	
Drain-Source Voltage		V_{DS}	30	V	
Gate-Source Voltage		V_{GS}	<u>+</u> 20	V	
Continuous Drain Current	T _C =25°C	I _D	15		
Pulsed Drain Current(Note 1)	T _C =25°C	I _{DM}	60	Α	
Power Dissipation	Tc=25°C	P _D	31	W	
Continuous Drain Current	T _A =25°C	I _D	15	Α	
Power Dissipation	T _A =25°C	P _D	2.0	W	
Operating Junction and Storage Temperature Range		T_J, T_{STG}	-55~150	°C	
Typical Thermal Resistance ^(Note 4,5)	Junction to Case	$R_{ heta JC}$	4.0	°C/W	
	Junction to Ambient	$R_{\theta JA}$	62.5		

• Limited only By Maximum Junction Temperature



Electrical Characteristics (T_A=25 °C unless otherwise noted)

PARAMETER	SYMBOL	TEST CONDITION	MIN.	TYP.	MAX.	UNITS
Static						
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V,I _D =250uA	30	-	-	V
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =250uA	1.0	1.6	2.5	V
Drain-Source On-State Resistance	R _{DS(on)}	V _{GS} =10V,I _D =10A	-	5	6	mΩ
		V _{GS} =4.5V,I _D =8A	-	6.6	9	
Zero Gate Voltage Drain Current	I _{DSS}	V _{DS} =30V,V _{GS} =0V	-	-	1.0	uA
Gate-Source Leakage Current	I _{GSS}	V _{GS} = <u>+</u> 20V,V _{DS} =0V	-	-	<u>+</u> 100	nA
Dynamic (Note 6)						
Total Gate Charge	Q_g	V _{DS} =15V, I _D =20A, V _{GS} =4.5V (Note 1,2)	-	12	-	nC
Gate-Source Charge	Q_{gs}		-	3.8	-	
Gate-Drain Charge	Q_{gd}	V _{GS} -4.5V	-	4.3	-	
Input Capacitance	Ciss), O5),), O),	-	1323	-	pF
Output Capacitance	Coss	V _{DS} =25V, V _{GS} =0V,	-	219	-	
Reverse Transfer Capacitance	Crss	f=1.0MHZ	-	136	-	
Turn-On Delay Time	td _(on)	V_{DS} =15V,RL=1 Ω , V_{GS} =10V, R _G =3.3 Ω	-	5.0	-	
Turn-On Rise Time	t _r		-	42	-	ns
Turn-Off Delay Time	td _(off)	(Note 2,3)	-	36	-	
Turn-Off Fall Time	t _f		-	5.5	-	
Drain-Source Diode						
Maximum Continuous Drain-Source			-	-	60	Α
Diode Forward Current	Is					
Diode Forward Voltage	V _{SD}	I _S =1A,V _{GS} =0V	-	0.83	1	V

NOTES:

- 1. Pulse width < 300 us, Duty cycle < 2%
- 2. Essentially independent of operating temperature typical characteristics
- 3. Repetitive rating, pulse width limited by junction temperature T_{J(MAX)}=150°C. Ratings are based on low frequency and duty cycles to keep initial T_J =25°C.
- 4. The maximum current rating is package limited
- 5. R_{OJA} is the sum of the junction-to-case and case-to-ambient thermal resistance where the case thermal reference is defined as the solder mounting surface of the drain pins. Mounted on a 1 inch² with 2oz.square pad of copper
- 6. Guaranteed by design, not subject to production testing.



TYPICAL CHARACTERISTIC CURVES

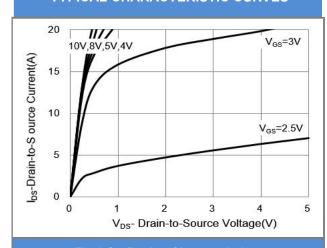


Fig.1 On-Region Characteristics

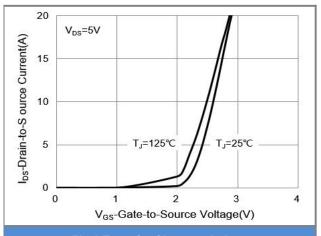


Fig.2 Transfer Characteristics

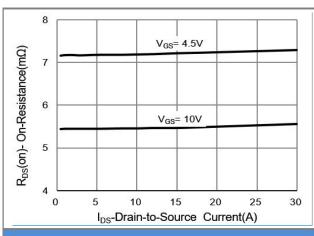


Fig.3 On-Resistance vs. Drain Current

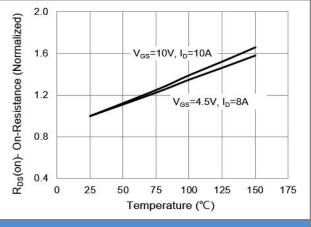


Fig.4 On-Resistance vs. Junction temperature

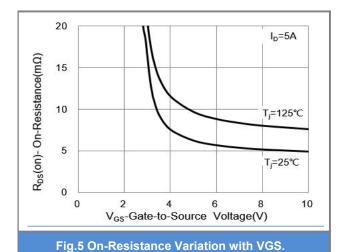
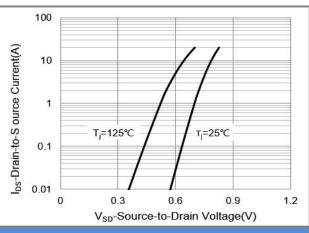


Fig.6 Source-Drain Diode Forward Voltage





TYPICAL CHARACTERISTIC CURVES

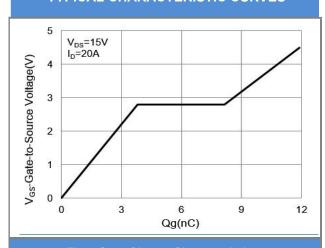


Fig.7 Gate-Charge Characteristics

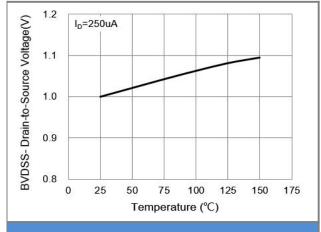


Fig.8 Breakdown Voltage Variation vs. Temperature.

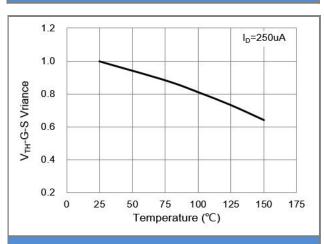


Fig.9 Threshold Voltage Variation with Temperature

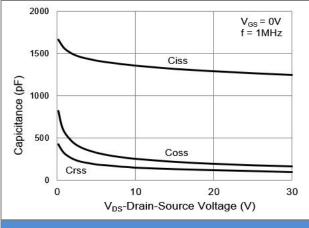
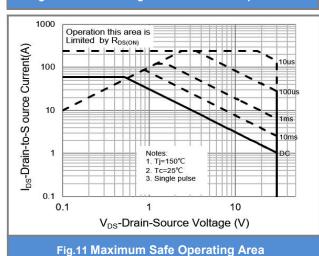


Fig.10 Capacitance vs. Drain-Source Voltage.





TYPICAL CHARACTERISTIC CURVES

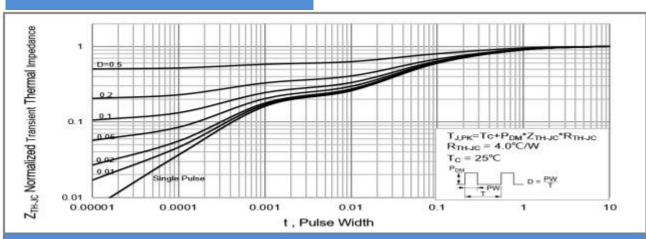


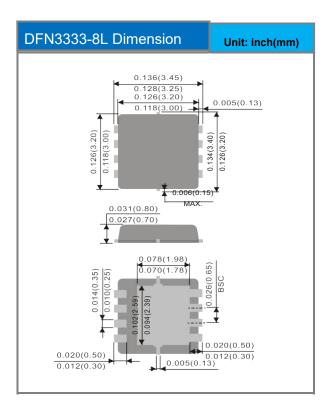
Fig.12 Normalized Transient Thermal Impedance vs. Pulse Width

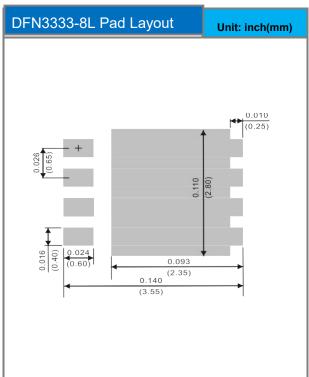


Part No Packing Code Version

Part No Packing Code	Package Type	Packing Type			
CSM320N15D3-3	DFN3333-8L	5K pcs / 13" reel			

Packaging Information & Mounting Pad Layout







Notice

Specifications of the products displayed herein are subject to change without notice.

CCS or anyone on its behalf, assumes no responsibility or liability for any errors or inaccuracies.

Information contained herein is intended to provide a product description only. No lice nse, express or implied, to any intellectual property rights is granted by this document. E xcept as provided in CCS terms and conditions of sale for such products, CCS assumes no liability whatsoever, and disclaims any express or implied warranty, relating to sale a nd/or use of CCS products including liability or warranties relating to fitness for a particul ar purpose, merchant ability, or infringement of any patent, copyright, or other intellectual property right.

The products shown herein are not designed for use in medical, life-saving, or lifesustaining applications.

Customers using or selling these products for use in such applications do so at their ow n risk and agree to fully indemnify CCS for any damages resulting from such improper use or sale.